

G1A THRU G1M

Technical Data Data Sheet N1731, Rev. A

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G1A-G1M 1.0AMP SURFACE MOUNT GLASS RECOVERY RECTIFIER



Features

- For surface mounted application
- Low forward voltage drop
- High current capability
- High reliability
- Classification Rating 94V- 0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: JEDEC SMAF molded plastic body
- Terminals: leads solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.038 grams
- Mounting Position: Any

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Type Number	Symbol	G1A	G1B	G1D	G1G	G1J	G1K	G1M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average forward rectified output current @T _A = 75°C	lo	1.0			А				
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	35		А					
Forward Voltage @I _F =1.0A	VF	1.1		V					
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	IRM	5.0 500		μA					
ypical Junction Capacitance (Note 1) C _J 12			pF						
Typical Thermal Resistance Junction to Ambient (Note 2)	R _{0JA}				30				°C/W
Operating and Storage Temperature Range	T _J , T _{STG}			-5	55 to +15	50			°C

Note: 1. Measured at 1.0 MHz and Applied reverse Voltage of 4.0V D.C 2. Resistance from Junction to Ambient at 0.375(9.5mm) lead length .

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Ratings and Characteristics Curves

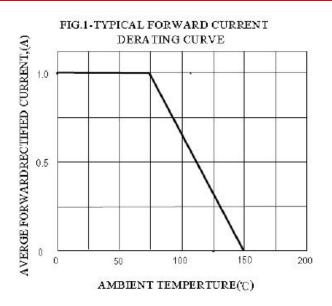
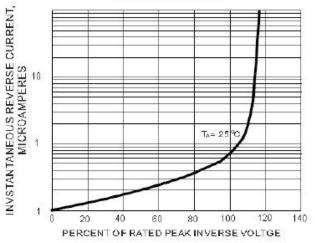


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS INSTANEOUS FORWARD CURRENT,(A) 10.0 1.0 = 25°C Pulse Width=300 # s 1% Duty Cycle 1 .01 1.1 5 1.4 .8 1.7 INSTANEOUS FORWARD VOLTAGE,(V)

FIG.3-MAXIMUN NON-REPETITIVE FORWARD SURGE CURRENT

KINNDED OF OVELES AT COUR

FIG.4-TYPICAL REVERSE CHARACTERISTICS



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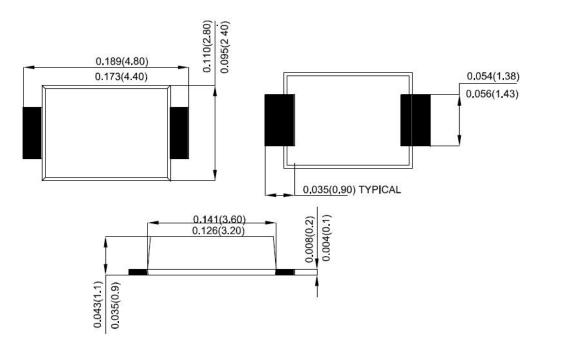
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Mechanical Dimensions SMAF(Millimeters/Inches)

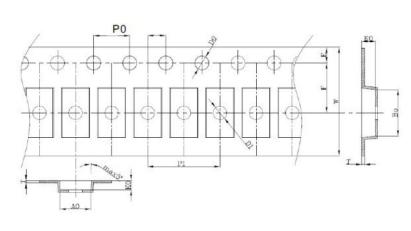


Ordering Information

Device	Package	Shipping
G1A		
THRU	SMAF (Pb-Free)	3000pcs / reel
G1M		·

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

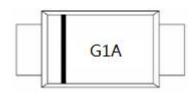
Carrier Tape Specification SMAF



SYMBOL	Millimeters				
STWBUL	Min.	Max.			
A0	2.83	3.03			
B0	2.23	5.43			
K0	1.23	1.43			
P0	3.90	4.10			
P1	3.90	4.10			
P2	1.90	2.10			
Т	0.17	0.23			
E	1.63	1.83			
F	5.45	5.65			
D0	1.50	1.60			
D1	1.45	1.55			
W	11.70	12.30			

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Marking Diagram



G1A = Type Number



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